

General Description

The MAX4780/MAX4784 are low on-resistance, lowvoltage, quad 2:1 analog multiplexers that operate from a single +1.6V to +4.2V supply. These devices have fast switching speeds (ton = 20ns, toff = 8ns), handle rail-to-rail analog signals, and consume less than 1µW of quiescent power.

When powered from a +2.7V supply, the MAX4780/ MAX4784 feature low 0.7Ω on-resistance (R_{ON}), and 0.1Ω Ron flatness. The digital logic input is +1.8V CMOS-logic compatible when using a single +3V supply.

The MAX4780/MAX4784 are available in 16-pin TSSOP and 3mm x 3mm thin QFN packages.

Applications

Power Routing

Battery-Powered Systems

Audio and Video Signal Routing

Low-Voltage Data-Acquisition Systems

Communications Circuits

PCMCIA Cards

Cellular Phones

Modems

Hard Drives

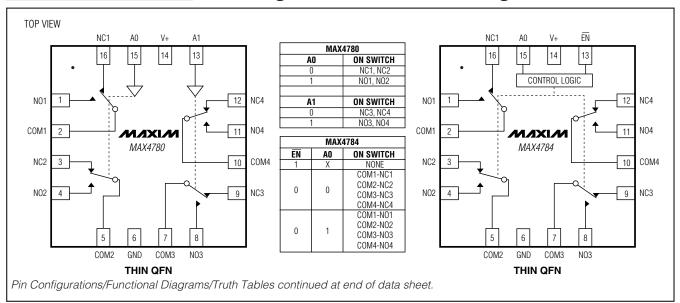
Features

- ♦ Single-Supply Operation from 1.6V to 4.2V
- ♦ Low Ron 0.7Ω (+2.7V Supply) 2Ω (+1.8V Supply)
- ♦ 0.1Ω Ron Flatness (+2.7V Supply)
- ♦ 3mm x 3mm Thin QFN Package
- ♦ +1.8V CMOS Logic Compatible
- ♦ Fast Switching: toN = 20ns, toFF = 8ns

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX4780ETE	-40°C to +85°C	16 Thin QFN
MAX4780EUE	-40°C to +85°C	16 TSSOP
MAX4784ETE	-40°C to +85°C	16 Thin QFN
MAX4784EUE	-40°C to +85°C	16 TSSOP

Pin Configurations/Functional Diagrams/Truth Tables



Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND	
V+, A_, EN	0.3V to +4.6V
COM_, NO_, NC_ (Note 1)	0.3V to $(V+ + 0.3V)$
Continuous Current COM_, NO_, NC	±300mA
Peak Current COM_, NO_, NC_	
(pulsed at 1ms 10% duty cycle)	±500mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
16-Pin Thin QFN (derate 14.7mW/°C	
above +70°C)	1176.5mW
16-Pin TSSOP (derate 9.4mW/°C above +70°C)	755mW
Operating Temperature Range40	°C to +85°C
Maximum Junction Temperature	+150°C
Storage Temperature Range65°	C to +150°C

Note 1: Signals on COM_, NO_, or NC_ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V+ = +2.7V \text{ to } +4.2V, V_{IH} = +1.4V, V_{IL} = +0.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V+ = +3.0V, T_A = +25^{\circ}C.)$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
ANALOG SWITCH							•	
Analog Signal Range	V _{COM} _, V _{NO} _, V _{NC} _			0		V+	V	
On-Resistance (Note 4)	Ron	V+ = 2.7V, ICOM = 100mA,	+25°C		0.7	1	Ω	
On-nesistance (Note 4)	HOM	V_{NO} or V_{NC} = 1.5V	T _{MIN} to T _{MAX}			1.2	22	
On-Resistance Match Between Channels	ΔRon	V+ = 2.7V, I _{COM} _ = 100mA,	+25°C		0.1	0.15	Ω	
(Notes 4, 5)	Anon	V_{NO} or V_{NC} = 1.5V	T _{MIN} to T _{MAX}			0.2	_ \(\Omega\)	
On-Resistance Flatness	Dei verovi	V+ = 2.7V, I _{COM} _ = 100mA,	+25°C		0.1	0.2	Ω	
(Note 6)	RFLAT(ON)	V_{NO} or $V_{NC} = 1V$, 1.5V, 2V	T _{MIN} to T _{MAX}			0.3	22	
NO_ or NC_ Off-Leakage	I _{NO_(OFF)} ,	V+ = 3.6V, V _{COM} _ = 0.3V, 3.3V,	+25°C	-1	±0.002	+1	nA	
Current (Note 7)	INC_(OFF)	V_{NO} or V_{NC} = 3.3V, 0.3V	T _{MIN} to T _{MAX}	-5		+5	IIA	
COM_ Off-Leakage Current		V + = 3.6V, $V_{COM} = 0.3V, 3.3V,$	+25°C	-1	±0.002	+1		
(MAX4784 Only) (Note 7)	ICOM_(OFF)	V_{NO} or V_{NC} = 3.3V, 0.3V, or floating	T _{MIN} to T _{MAX}	-5		+5	nA	
COM_ On-Leakage Current	LOOM (OND	V+ = 3.6V, $V_{COM} = 3.3V, 0.3V,$	+25°C	-2	±0.002	+2	nΔ	
(Note 7)	ICOM_(ON)	V_{NO} or V_{NC} = 3.3V, 0.3V, or floating	T _{MIN} to T _{MAX}	-10		+10	nA nA	

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ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

 $(V+=+2.7V \text{ to } +4.2V, V_{IH}=+1.4V, V_{IL}=+0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified.}$ Typical values are at $V+=+3.0V, T_A=+25^{\circ}C.)$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS				
SWITCH DYNAMIC CHARACTERISTICS											
Turn-On Time	ton	$V_{NO_{-}}, V_{NC_{-}} = 1.5V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		20	25	ns				
	3011	Figure 1	T _{MIN} to T _{MAX}			30					
Turn-Off Time	+0==	V_{NO} , V_{NC} = 1.5V, R_L = 50 Ω , C_L = 35pF,	+25°C		8	10	ns				
Turri-On Time	toff	Figure 1	T _{MIN} to T _{MAX}			18	115				
Drael, Defere Make (Nete O)	.	V _{NO} _, V _{NC} _ = 1.5V,	+25°C		7						
Break-Before-Make (Note 8)	[†] BBM	$R_L = 50\Omega$, $C_L = 35pF$, Figure 2	T _{MIN} to T _{MAX}	1			ns				
Charge Injection	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1.0$ nF, Figure 3	+25°C		5		рС				
NO_ or NC_ Off-Capacitance	Coff	f = 1MHz, Figure 4	+25°C		33		pF				
COM_ Off-Capacitance	CCOM_(OFF)	f = 1MHz, Figure 4	+25°C		60		рF				
COM_ On-Capacitance	C _{COM} (ON)	f = 1MHz, Figure 4	+25°C		85		pF				
-3dB On-Channel Bandwidth	BW	Signal = 0, $R_{IN} = R_{OUT} = 50\Omega$, $C_L = 5pF$, Figure 5			123		MHz				
Off-Isolation (Note 9)	V _{ISO}	$f = 1MHz$, $V_{COM} = 1V_{P-P}$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 5	+25°C		-67		dB				
Crosstalk (Note 10)	Vст	$f = 1MHz$, $V_{COM} = 1V_{P-P}$, $R_L = 50\Omega$, $C_L = 5pF$, Figures 4, 5	+25°C		-95		dB				
Total Harmonic Distortion	THD	f = 20Hz to 20 kHz, $V_{COM} = 2$ V $_{P-P}$, $R_L = 32$ Ω	+25°C		0.008		%				
LOGIC INPUT (A_, EN)											
Input Logic High	VIH			1.8			V				
Input Logic Low	VIL					0.5	V				
Input Leakage Current	IIN	$V_{\overline{EN}} = 0 \text{ or } +3.6V,$ $V_{A0} = 0 \text{ or } +3.6V$		-1	0.005	+1	μΑ				
POWER SUPPLY	•						•				
Power-Supply Range	V+			1.6		3.6	V				
Positive Supply Current	l+	$V+ = 3.6V$, \overline{EN} , $A0 = 0$ or $V+$, all channels on or off	T _{MIN} to T _{MAX}			2	μΑ				

ELECTRICAL CHARACTERISTICS—Single +1.8V Supply

 $(V+=+1.8V, V_{IH}=+1.0V, V_{IL}=+0.4V, T_A=T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical values are at $T_A=+25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
ANALOG SWITCH	•						•	
Analog Signal Range	V _{COM} _, V _{NO} _, V _{NC} _			0		V+	V	
On-Resistance	R _{ON}	I _{COM} _ = 10mA, V _{NO} _ or V _{NC} _ = 1.0V	+25°C		2	3 5	Ω	
			T _{MIN} to T _{MAX}					
NO_ or NC_ Off-Leakage	INO_(OFF),	$V_{COM} = 0.3V, 1.5V,$ V_{NO} or $V_{NC} = 1.5V,$	+25°C	-1		+1	nA	
Current (Note 7)	INC_(OFF)	0.3V	T _{MIN} to T _{MAX}	-5		+5		
COM_ Off-Leakage Current	ICOM (OFF)	$V_{COM} = 0.3V, 1.5V,$ V_{NO} or $V_{NC} = 1.5V,$	+25°C	-1		+1	n A	
(MAX4784 Only) (Note 7)	ICOM_(OFF)	0.3V	T _{MIN} to T _{MAX}	-5		+5		
COM_ On-Leakage Current	ICOM_(ON)	$V_{COM} = 0.3V, 1.5V, V_{NO} \text{ or } V_{NC} = 0.3V, 1.5V, 1.5V, or floating}$	+25°C	-2		+2	nA	
(Note 7)			T _{MIN} to T _{MAX}	-10		+10	TIA.	
SWITCH DYNAMIC CHARACTE	RISTICS						•	
Turn-On Time	ton	$V_{NO_{-}}, V_{NC_{-}} = 1.0V,$ $R_{I} = 50\Omega, C_{I} = 35pF,$	+25°C		25	30	ns	
Turr-On Time	ton	Figure 1	T _{MIN} to T _{MAX}			35	115	
T 0"T		V _{NO} _, V _{NC} _ = 1.0V,	+25°C		10	15		
Turn-Off Time	toff	$R_L = 50\Omega$, $C_L = 35pF$, Figure 1	T _{MIN} to T _{MAX}			20	ns	
Dreeds Defers Make (Nets 2)		V _{NO_} , V _{NC_} = 1.0V,	+25°C		10			
Break-Before-Make (Note 8)	tBBM	$R_L = 50\Omega$, $C_L = 35pF$, Figure 2	T _{MIN} to T _{MAX}	1			ns	
Charge Injection	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1$ nF, Figure 3	+25°C		5		рС	

ELECTRICAL CHARACTERISTICS—Single +1.8V Supply (continued)

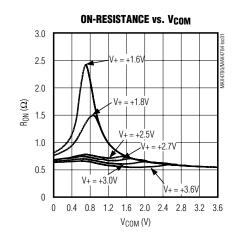
 $(V+=+1.8V, V_{IH}=+1.0V, V_{IL}=+0.4V, T_A=T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical values are at $T_A=+25^{\circ}C.$) (Notes 2, 3)

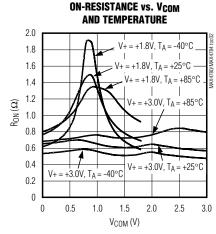
PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
LOGIC INPUT (A_, \overline{EN})							
Input Logic High	VIH			1.8			V
Input Logic Low	VIL					0.4	V
Input Leakage Current	I _{IN}	$V_{\overline{EN}} = 0 \text{ or } +3.6V,$ $V_{A0} = 0 \text{ or } +3.6V$		-1		+1	μΑ

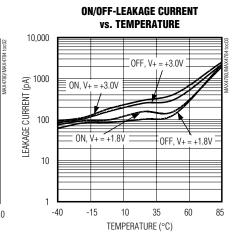
- **Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.
- **Note 3:** -40°C specifications are guaranteed by design.
- Note 4: R_{ON} and ΔR_{ON} matching specifications for QFN packaged parts are guaranteed by design.
- **Note 5:** $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 6:** Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.
- **Note 7:** Leakage parameters are 100% tested at $T_A = +85^{\circ}$ C, and guaranteed by correlation over the full rated temperature range.
- Note 8: Guaranteed by design.
- **Note 9:** Off-isolation = $20\log_{10}(V_{COM}/V_{NO})$, V_{COM} = output, V_{NO} = input to off switch.
- Note 10: Between two switches.
- **Note 11:** Parts are guaranteed to 1 million cycles of operation. (Cycle = switch on \rightarrow switch off \rightarrow switch on.)
- **Note 12:** The minimum load resistance is 8Ω . (See the *Typical Application Circuit.*)

Typical Operating Characteristics

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

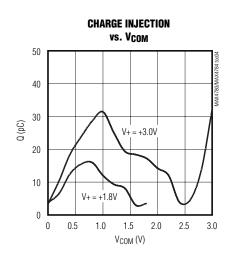


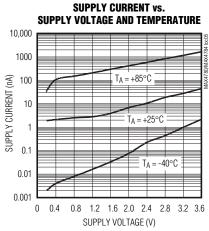


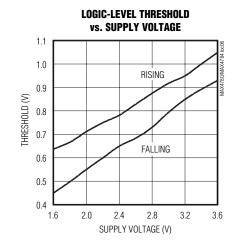


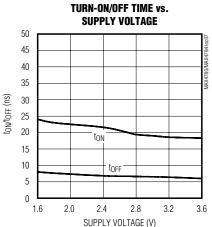
Typical Operating Characteristics (continued)

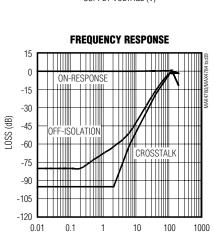
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



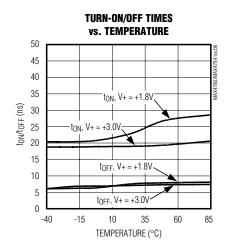


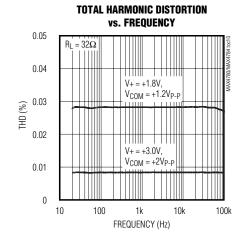






FREQUENCY (MHz)





Pin Description

	PI	N			
MAX	(4780	MAX	(4784	NAME	FUNCTION
TSSOP	THIN QFN	TSSOP	THIN QFN		
1	15	1	15	A0	Address Input
2	16	2	16	NC1	Normally Closed Terminal
3	1	3	1	NO1	Normally Open Terminal
4	2	4	2	COM1	Analog Switch Common Terminal
5	3	5	3	NC2	Normally Closed Terminal
6	4	6	4	NO2	Normally Open Terminal
7	5	7	5	COM2	Analog Switch Common Terminal
8	6	8	6	GND	Ground
9	7	9	7	COM3	Analog Switch Common Terminal
10	8	10	8	NO3	Normally Open Terminal
11	9	11	9	NC3	Normally Closed Terminal
12	10	12	10	COM4	Analog Switch Common Terminal
13	11	13	11	NO4	Normally Open Terminal
14	12	14	12	NC4	Normally Closed Terminal
15	13		_	A1	Address Input
_		15	13	ĒN	Enable. Connect to GND for normal operation. Connect to logic-level high to turn all switches off.
16	14	16	14	V+	Positive Supply Voltage

Detailed Description

The MAX4780/MAX4784 are low 0.7Ω (at V+ = +2.7V) on-resistance, low-voltage, quad 2:1 analog multiplexers/ demultiplexers that operate from a +1.6V to +4.2V single supply. CMOS switch construction allows switching analog signals that are within the supply voltage range (GND to V+).

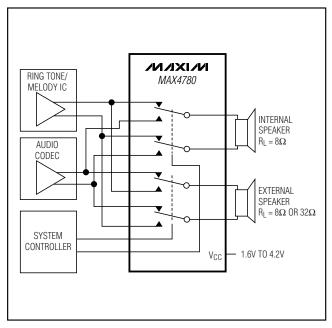
When powered from a +2.7V supply, the 0.7Ω R_{ON} allows high continuous currents to be switched in a variety of applications.

_Applications Information

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by NO_, NC_, or COM_.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V+ supply to other components. A $0.1\mu F$ capacitor, connected from V+ to GND, is adequate for most applications.

Typical Application Circuit



Logic Inputs

The MAX4780/MAX4784 logic inputs can be driven up to +4.2V regardless of the supply voltage. For example, with a +1.8V supply, A_ and EN may be driven low to GND and high to +4.2V. Driving A_ and EN rail-to-rail minimizes power consumption. Drive EN low to enable the COM_ outputs. When EN is high, the COM_ outputs are high impedance.

Analog Signal Levels

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in on-

resistance (see the *Typical Operating Characteristics*). The switches are bidirectional, so the NO_, NC_, and COM_ pins can be used as either inputs or outputs.

Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

Test Circuits/Timing Diagrams

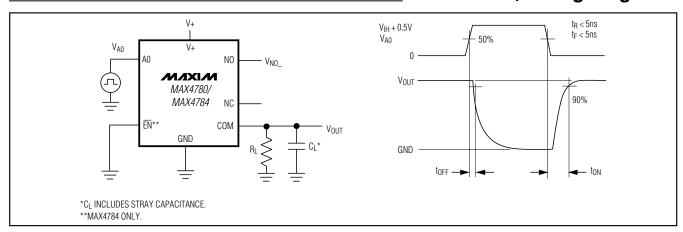


Figure 1. Turn-On and Turn-Off Times

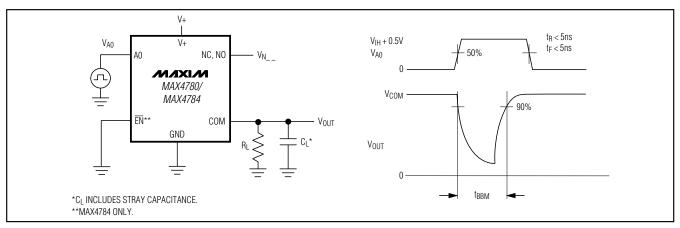


Figure 2. Break-Before-Make Interval

Test Circuits/Timing Diagrams (continued)

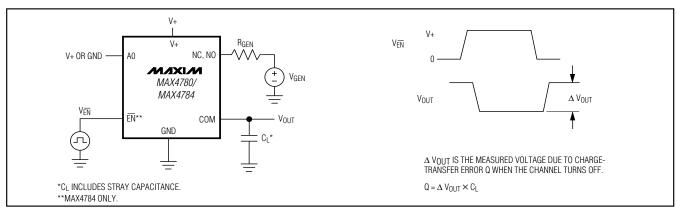


Figure 3. Charge Injection

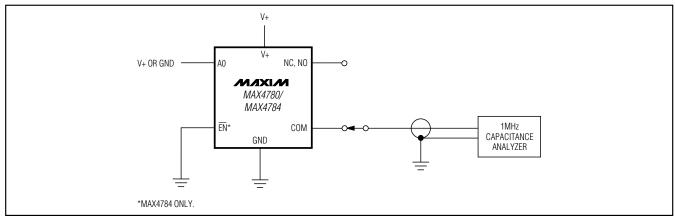


Figure 4. Capacitance

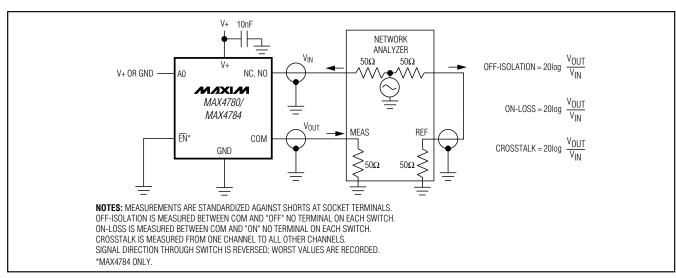
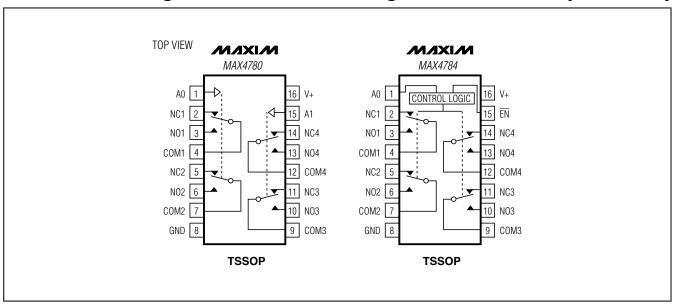


Figure 5. Off-Isolation, On-Loss, and Crosstalk

Pin Configurations/Functional Diagrams/Truth Tables (continued)



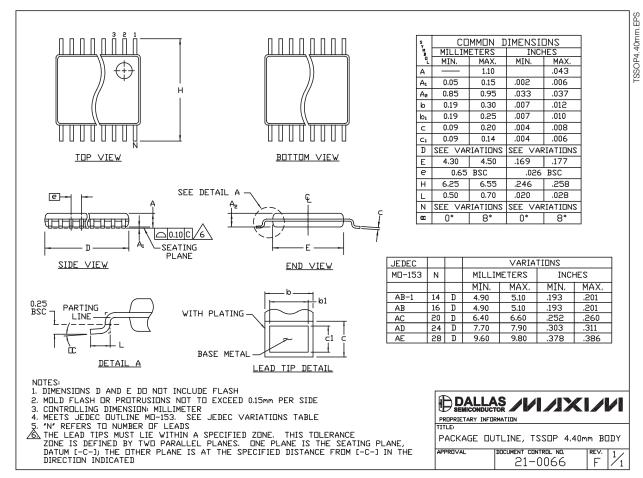
Chip Information

TRANSISTOR COUNT: 543
PROCESS: CMOS

MIXINN

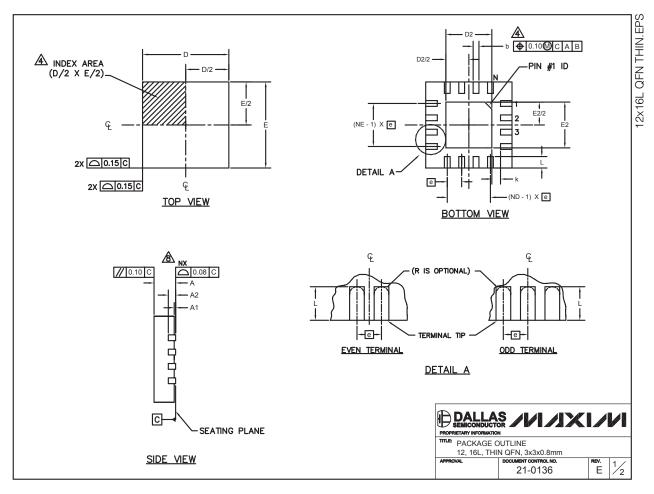
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

PKG		12L 3x3			16L 3x3	
REF.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	0.70	0.75	0.80	0.70	0.75	0.80
b	0.20	0.25	0.30	0.20	0.25	0.30
D	2.90	3.00	3.10	2.90	3.00	3.10
Е	2.90	3.00	3.10	2.90	3.00	3.10
е	0.50 BSC. 0.50 BSC.					
L	0.45 0.55		0.65	0.30	0.40	0.50
N		12			16	
ND	3				4	
NE		3			4	
A1	0 0.02		0.05	0 0.02		0.05
A2		0.20 REF			0.20 REF	
k	0.25	-	-	0.25	-	-

	EXPOSED PAD VARIATIONS												
PKG.	D2				E2		PIN ID	JEDEC	DOWN BONDS				
CODES	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	FINID	JEDEC	ALLOWED				
T1233-1	0.95	1.10	1.25	0.95	1.10	1.25	0.35 x 45∞	WEED-1	NO				
T1233-3	0.95	1.10	1.25	0.95	1.10	1.25	0.35 x 45∞	WEED-1	YES				
T1633-1	0.95	1.10	1.25	0.95	1.10	1.25	0.35 x 45∞	WEED-2	NO				
T1633-2	0.95	1.10	1.25	0.95	1.10	1.25	0.35 x 45∞	WEED-2	YES				
T1633F-3	0.65	0.80	0.95	0.65	0.80	0.95	0.225 x 45∞	WEED-2	N/A				
T1633-4	0.95	1.10	1.25	0.95	1.10	1.25	0.35 x 45∞	WEED-2	NO				

NOTES:

- 1. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
- 2. ALL DIMENSIONS ARE IN MILLIMETERS. ANGLES ARE IN DEGREES.
- 3. N IS THE TOTAL NUMBER OF TERMINALS.
- THE TERMINAL #1 IDENTIFIER AND TERMINAL NUMBERING CONVENTION SHALL CONFORM TO JESD 95-1 SPP-012. DETAILS OF TERMINAL #1 IDENTIFIER ARE OPTIONAL, BUT MUST BE LOCATED WITHIN THE ZONE INDICATED. THE TERMINAL #1 IDENTIFIER MAY BE EITHER A MOLD OR MARKED FEAT IJES.
- ⚠ DIMENSION b APPLIES TO METALLIZED TERMINAL AND IS MEASURED BETWEEN 0.20 mm AND 0.25 mm FROM TERMINAL TIP.
- ⚠ ND AND NE REFER TO THE NUMBER OF TERMINALS ON EACH D AND E SIDE RESPECTIVELY.
- 7. DEPOPULATION IS POSSIBLE IN A SYMMETRICAL FASHION.
- ▲ COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.
- 9. DRAWING CONFORMS TO JEDEC MO220 REVISION C.



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

WHAT'S NEWPRODUCTS SOLUTIONS DESIGN APPNOTES SUPPORT

BUY

COMPANY MEMBERS

MAX4780

Part Number Table

Notes:

- 1. See the MAX4780 QuickView Data Sheet for further information on this product family or download the MAX4780 full data sheet (PDF, 360kB).
- 2. Other options and links for purchasing parts are listed at: http://www.maxim-ic.com/sales.
- 3. <u>Didn't Find What You Need?</u> Ask our applications engineers. Expert assistance in finding parts, usually within one business day.
- 4. Part number suffixes: T or T&R = tape and reel; += RoHS/lead-free; #= RoHS/lead-exempt. More: See <u>full data sheet</u> or <u>Part Naming Conventions</u>.
- 5. * Some packages have variations, listed on the drawing. "PkgCode/Variation" tells which variation the product uses.

Part Number	Free Sample	Buy Direct	Package: TYPE PINS SIZE DRAWING CODE/VAR *	Temp	RoHS/Lead-Free? Materials Analysis
MAX4780ETE			THIN QFN;16 pin;3X3X0.8mm Dwg: 21-0136I (PDF) Use pkgcode/variation: T1633-4*	-40C to +85C	RoHS/Lead-Free: No Materials Analysis
MAX4780ETE-T			THIN QFN;16 pin;3X3X0.8mm Dwg: 21-0136I (PDF) Use pkgcode/variation: T1633-4*	-40C to +85C	RoHS/Lead-Free: No Materials Analysis
MAX4780ETE+			THIN QFN;16 pin;3X3X0.8mm Dwg: 21-0136I (PDF) Use pkgcode/variation: T1633+4*	-40C to +85C	RoHS/Lead-Free: Yes Materials Analysis

MAX4780ETE+T	THIN QFN;16 pin;3X3X0.8mm Dwg: 21-0136I (PDF) Use pkgcode/variation: T1633+4*	-40C to +85C	RoHS/Lead-Free: Yes Materials Analysis			
MAX4780EUE+	TSSOP;16 pin;4.4mm Dwg: 21-0066I (PDF) Use pkgcode/variation: U16+2*	-40C to +85C	RoHS/Lead-Free: Yes Materials Analysis			
MAX4780EUE+T		-40C to +85C	RoHS/Lead-Free: Yes			
MAX4780EUE	TSSOP;16 pin;4.4mm Dwg: <u>21-0066I</u> (PDF) Use pkgcode/variation: U16-2*	-40C to +85C	RoHS/Lead-Free: No Materials Analysis			
MAX4780EUE-T		-40C to +85C	RoHS/Lead-Free: No			
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